

N-Channel 100 V (D-S) 175 °C MOSFET

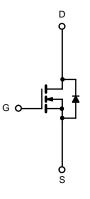
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
100	0.005 at V _{GS} = 10 V	110 ^a		

FEATURES

- TrenchFET[®] Power MOSFET
- New Package with Low Thermal Resistance
- 100 % R_g Tested







N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_{C} = 25 \text{ °C}$, unless otherwise noted							
Parameter	Symbol	Limit	Unit				
Drain-Source Voltage	V _{DS}	100	V				
Gate-Source Voltage		V _{GS}		± 20			
Continuous Drain Current (T ₁ = 175 °C)	T _C = 25 °C		110 ^a	А			
Continuous Drain Current $(T_j = TTS C)$	T _C = 125 °C	I _D	87 ^a				
Pulsed Drain Current		I _{DM}	440				
Avalanche Current		I _{AR}	75				
Repetitive Avalanche Energy ^b	L = 0.1 mH	E _{AR}	280	mJ			
Maximum Power Dissipation ^b	T _C = 25 °C	р	375 ^c	w			
	T _A = 25 °C	– P _D –	3.75				
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C			

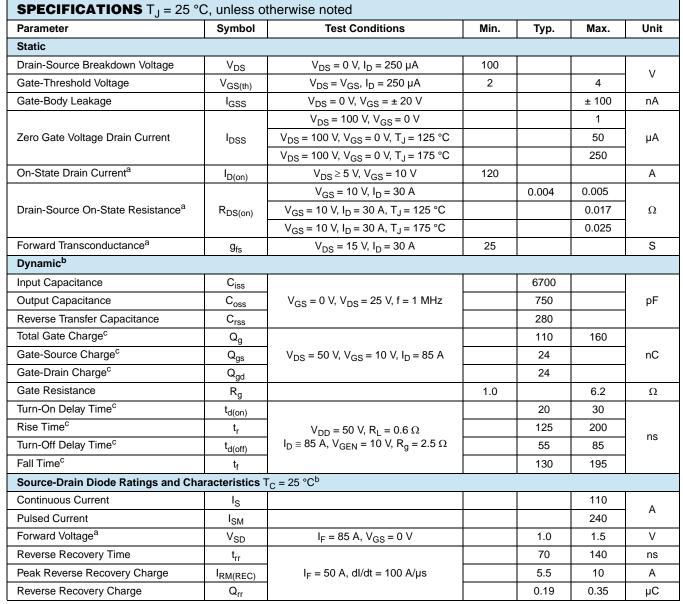
THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Limit	Unit			
Junction-to-Ambient	PCB Mount (TO-263) ^d	R _{thJA}	40	°C/W			
Junction-to-Case (Drain)		R _{thJC}	0.4	C/VV			

Notes:

a. Package limited.

a. Package infined.
b. Duty cycle ≤ 1 %.
c. See SOA curve for voltage derating.
d. When mounted on 1" square PCB (FR-4 material).

VBL1105



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Notes:

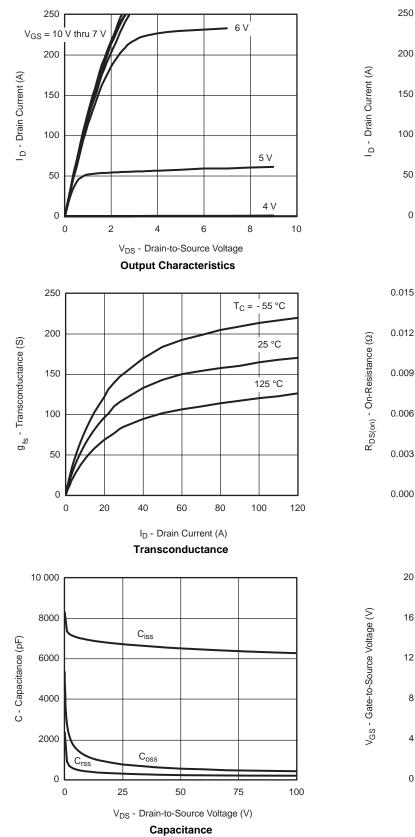
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

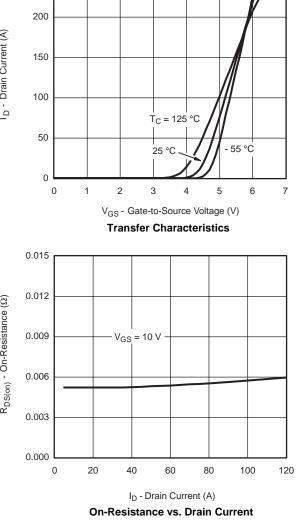
c. Independent of operating temperature.

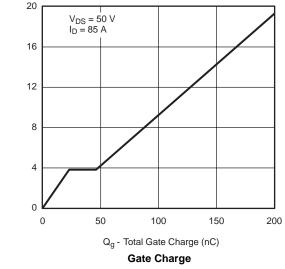
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





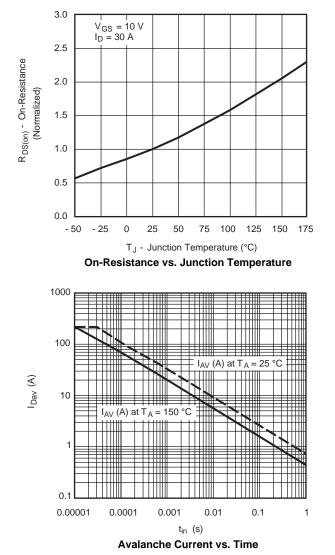
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

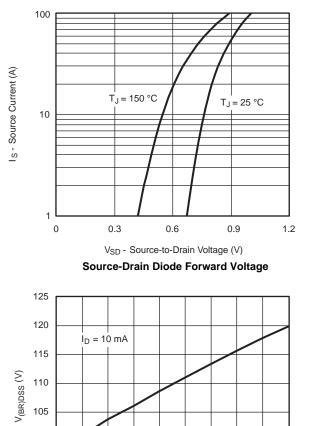






TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





100

95

90

- 50 - 25

0 25 50

75 100 125

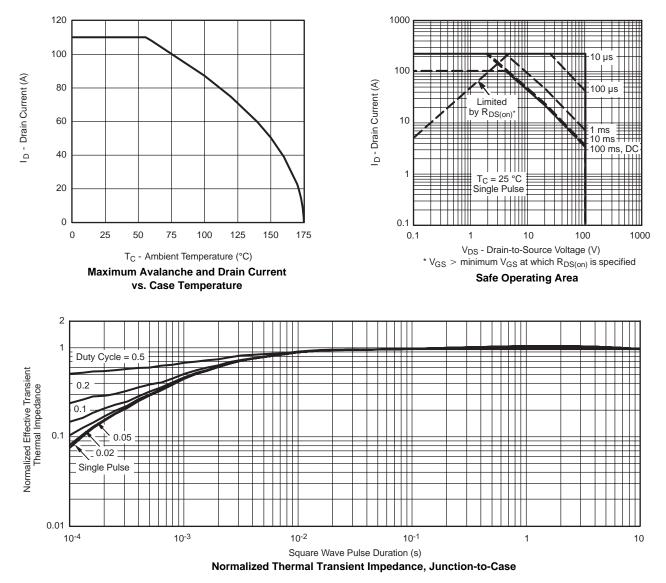
T_J - Junction Temperature (°C)

Drain Source Breakdown vs. Junction Temperature

150 175

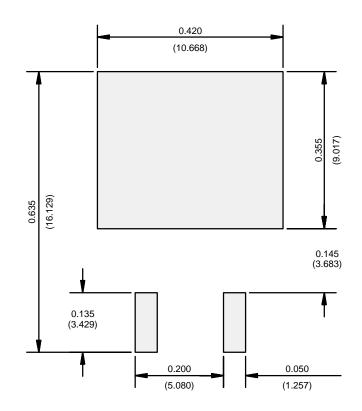


THERMAL RATINGS





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)



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